Transistor - Page 1 of 2



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# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

## Terminal Length:

0.312 inches

#### **Overall Height:**

Between 0.250 inches and 0.450 inches

## **Overall Width:**

1.050 inches

## Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

## **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

170.0 collector to base voltage/static/emitter open and 170.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

16.00 amperes repetitive peak forward current blank

#### Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Burn-in test requirements; junction pattern arrangement: npn

# Terminal Type And Quantity:

2 pin and 1 case

## Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# **NSN 5961-01-027-8749** Transistor - Page 2 of 2

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